

SANYO**2SB1204/2SD1804****High-Current Switching Applications****Applications**

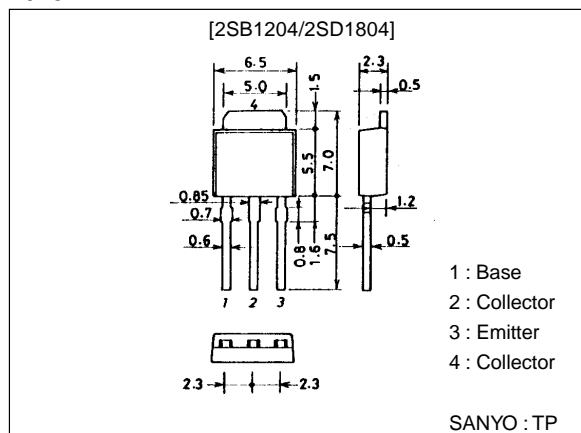
- Relay drivers, high-speed inverters, converters, and other general high-current switching applications.

Features

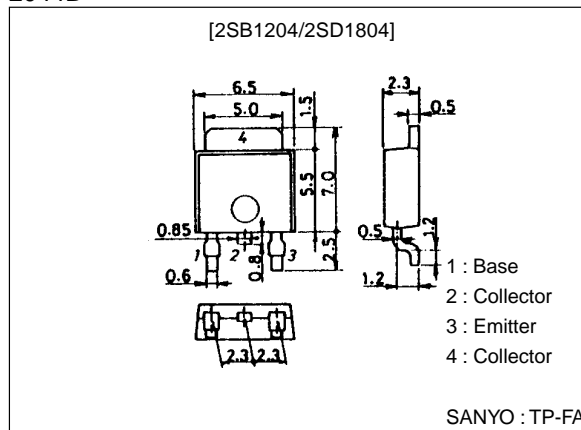
- Low collector-to-emitter saturation voltage.
- High current and high f_T .
- Excellent linearity of h_{FE} .
- Fast switching time.
- Small and slim package making it easy to make 2SB1204/2SD1804-applied sets smaller.

Package Dimensions

unit:mm

2045B

unit:mm

2044B

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92098HA (KT)/8309MO/3117AT, TS No.2086-1/5

() : 2SB1204

Specifications

Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V_{CBO}		(-)60	V
Collector-to-Emitter Voltage	V_{CEO}		(-)50	V
Emitter-to-Base Voltage	V_{EBO}		(-)6	V
Collector Current	I_C		(-)8	A
Collector Current (Pulse)	I_{CP}		(-)12	A
Collector Dissipation	P_C		1	W
		Tc=25°C	20	W
Junction Temperature	T_J		150	°C
Storage Temperature	T_{stg}		-55 to +150	°C

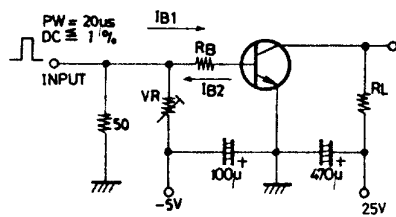
Electrical Characteristics at Ta = 25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector Cutoff Current	I_{CBO}	$V_{CB}=(-)40V, I_E=0$			(-)1	μA
Emitter Cutoff Current	I_{EBO}	$V_{EB}=(-)4V, I_C=0$			(-)1	μA
DC Current Gain	h_{FE1}	$V_{CE}=(-)2V, I_C=(-)0.5A$	70*		400*	
	h_{FE2}	$V_{CE}=(-)2V, I_C=(-)6A$	35			
Gain-Bandwidth Product	f_T	$V_{CE}=(-)5V, I_C=(-)1A$		(130)		MHz
				180		MHz
Output Capacitance	C_{ob}	$V_{CB}=(-)10V, f=1MHz$		(95)65		pF
Collector-to-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=(-)4A, I_B=(-)0.2A$		200	400	mV
				(-250)	(-500)	mV
Base-to-Emitter Saturation Voltage	$V_{BE(sat)}$	$I_C=(-)4A, I_B=(-)0.2A$		(-)0.95	(-)1.3	V
Collector-to-Base Breakdown Voltage	$V_{(BR)CBO}$	$I_C=(-)10μA, I_E=0$	(-)60			V
Collector-to-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C=(-)1mA, R_{BE}=∞$	(-)50			V
Emitter-to-Base Breakdown Voltage	$V_{(BR)EBO}$	$I_E=(-)10μA, I_C=0$	(-)6			V
Turn-ON Time	t_{on}	See specified Test Circuit		(50)		ns
Storage Time	t_{stg}	See specified Test Circuit		(450)		ns
				500		ns
Fall Time	t_f	See specified Test Circuit		20		ns

* : The 2SB1204/2SD1804 are classified by 0.5A h_{FE} as follows :

70	Q	140	100	R	200	140	S	280	200	T	400
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Switching Time Test Circuit

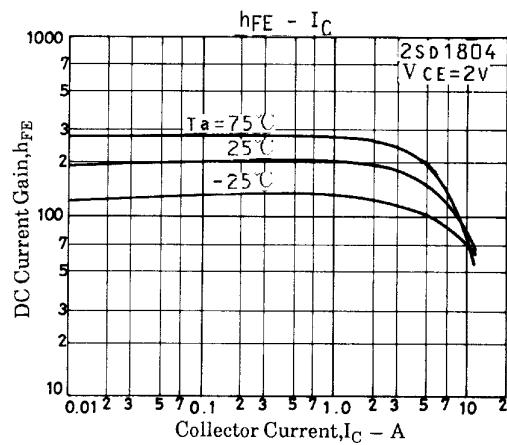
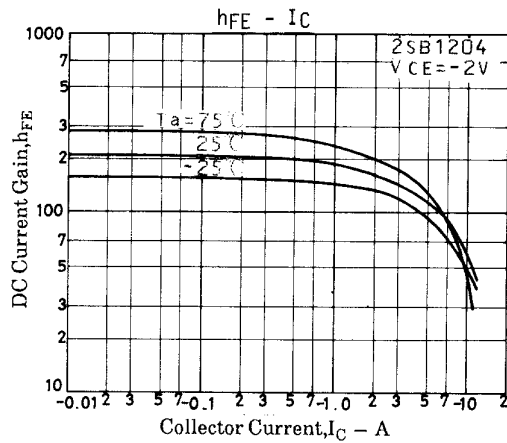
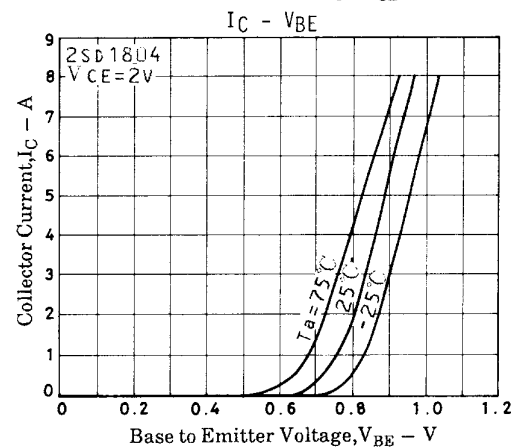
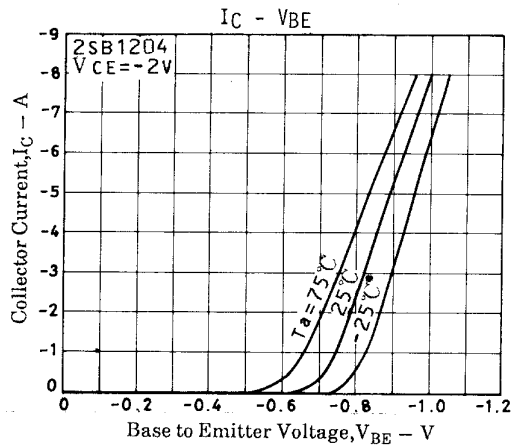
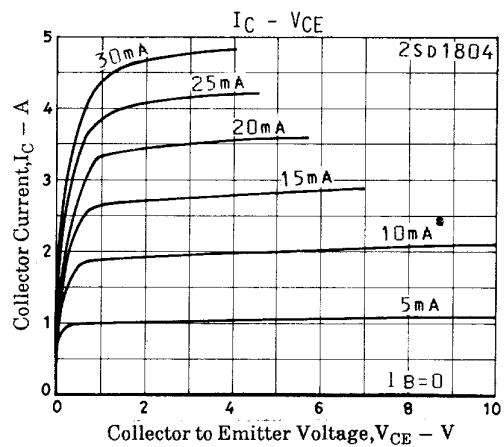
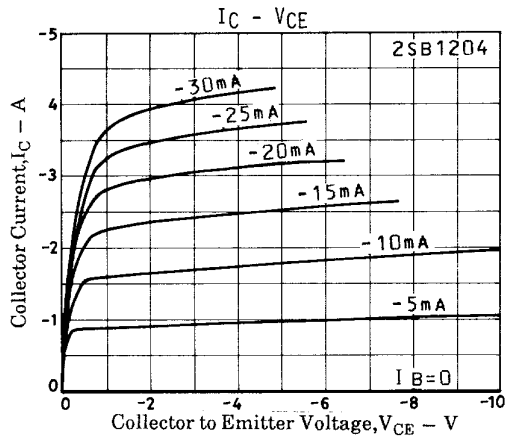
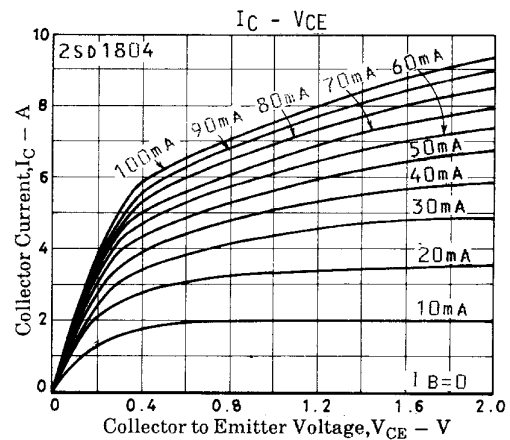
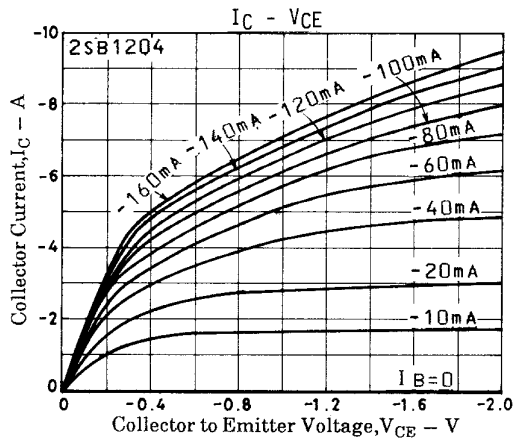


$$I_C = 10 \text{ A}, I_{B1} = -10 \text{ A}, I_{B2} = 4 \text{ A}$$

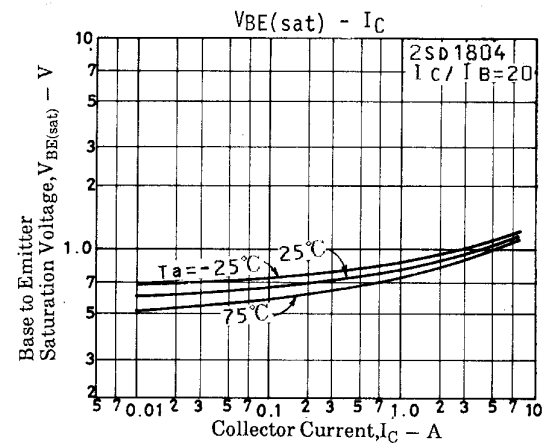
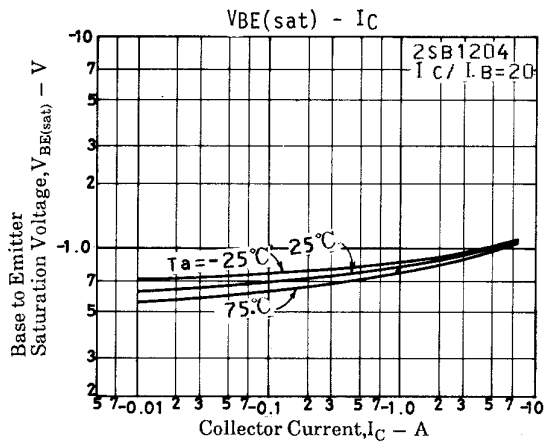
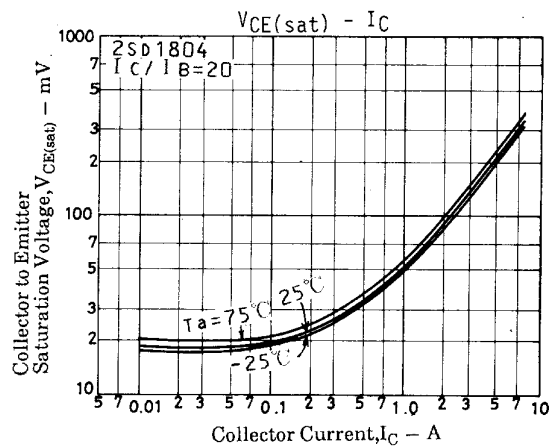
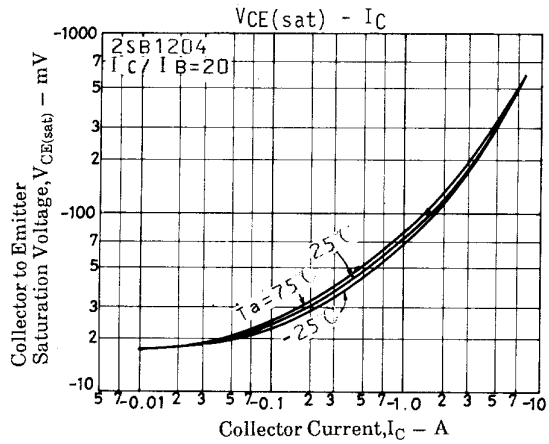
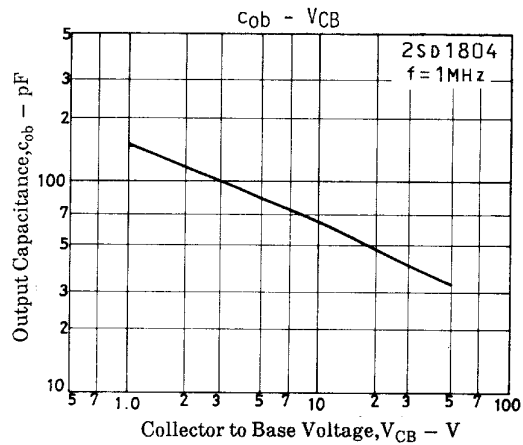
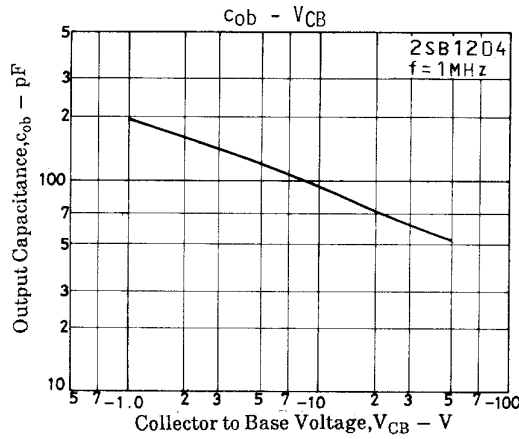
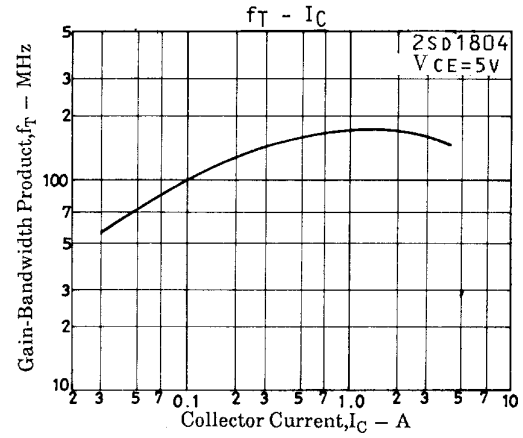
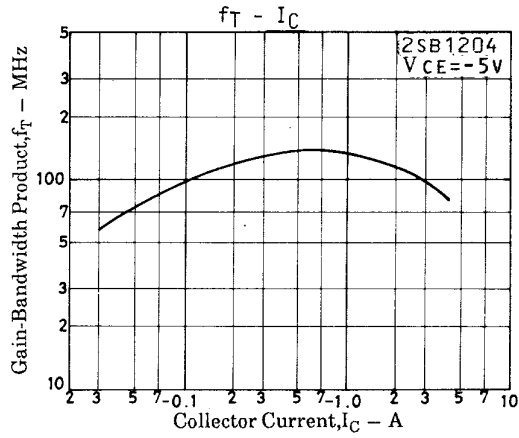
(For PNP, the polarity is reversed.)

Unit (resistance : Ω, capacitance : F)

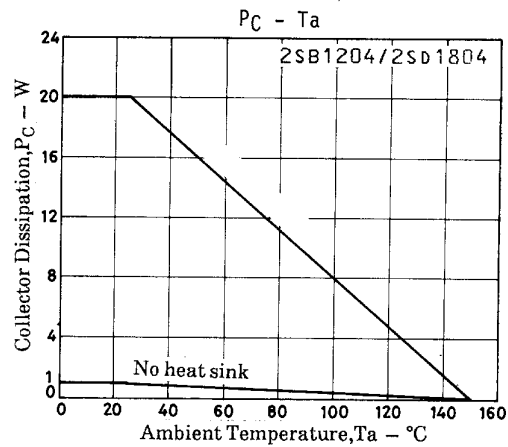
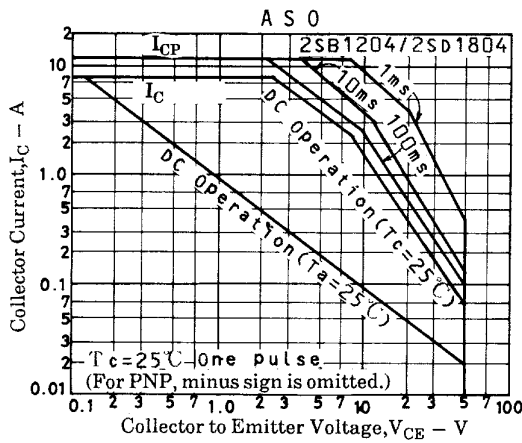
2SB1204/2SD1804



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